

Features:

- 650V Schottky Diode
- Zero Reverse Recovery Current
- High Frequency Operation
- Positive Temperature Coefficient
- Temperature independent Switching

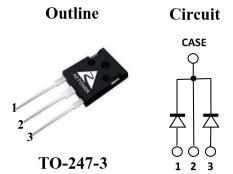
Benefits:

- Unipolar Rectifier
- Minimal switching loss
- Higher Efficiency
- Low cooling requirement

Symbol	Value	Unit		
$\mathbf{V}_{\mathbf{RRM}}$	650	V		
$I_F \; (T_c \!=\! 150^{\circ}\!C)$	30	A		
* Q c	38	пC		

Applications:

- Switch Mode Power Supply
- Booster diodes in PFC, DC/DC
- AC/DC converters



Maximum Ratings (*Per leg)

Symbol	Parameter	Value	Unit	Test Conditions
V_R	DC Peak Reverse Voltage	650	V	$T_J = 25^{\circ}C$
V _{RRM}	Repetitive Peak Reverse	650	V	$T_J = 25^{\circ}C$
V _{RSM}	Surge Peak Reverse Voltage	650	V	$T_J = 25^{\circ}C$
$\mathbf{I_F}$	Continuous Forward Current	*46/92 *21/42 *15/30	A	$T_{\rm C} = 25^{\circ}{\rm C}$ $T_{\rm C} = 135^{\circ}{\rm C}$ $T_{\rm C} = 150^{\circ}{\rm C}$
I _{FRM}	Repetitive Peak Forward Surge Current	*88 *79	A	$T_{\rm C}=25^{\circ}{\rm C},T_{\rm P}=10{\rm ms},{\rm HalfSineWave}$ $T_{\rm C}=125^{\circ}{\rm C},T_{\rm P}=10{\rm ms},{\rm HalfSineWave}$
I _{FSM}	Non-Repetitive Peak Forward Surge Current	*119 *107	A	$T_{C}=25^{\circ}\text{C}, T_{P}=10\text{ms}, \text{Half Sine Wave}$ $T_{C}=125^{\circ}\text{C}, T_{P}=10\text{ms}, \text{Half Sine Wave}$
P _D	Power Dissipation	*163 *54	W	$T_{\rm C} = 25^{\circ}{\rm C}$ $T_{\rm C} = 125^{\circ}{\rm C}$
T _{J,max}	Operating Junction Temperature	175	°C	
T _{stg}	Storage Temperature Range	-55 to 175	°C	



Thermal characteristics (*Per leg)

Symbol	Parameter	Min.	Тур.	Max.	Unit
R _{th} JC	Thermal resistance		*0.92/0.46		°C/W

Electrical Characteristics (Per leg)

Symbol	Parameter	Value		Unit	Test Conditions	
		Min.	Тур.	Max.	Unit	Test Conditions
V _{DC}	DC Blocking Voltage	650			V	$I_R = 100 \mu A, T_J = 25^{\circ} C$
V-	Forward Voltage		1.5	1.8	V	$I_F = 15A, T_J = 25^{\circ}C$
$\mathbf{V_F}$	Forward Voltage		1.9	2.2		$I_F = 15A, T_J = 175^{\circ}C$
I _R	Reverse Current		5	100	μΑ	$V_R = 650V, T_J = 25^{\circ}C$
			10	250		$V_R = 650V, T_J = 175^{\circ}C$
Qc	Total Capacitive Charge		38		пC	$I_F = 15A$, $dI/dt = 350A/\mu s$
						$T_J = 25^{\circ}C, V_R = 400V$
C	Total Capacitance		677		pF	$V_R = 1V, T_J = 25^{\circ}C, f = 1 \text{ MHz}$
			99			$V_R = 200V, T_J = 25^{\circ}C, f = 1 \text{ MHz}$
			97			$V_R = 400V, T_J = 25^{\circ}C, f = 1 \text{ MHz}$

Typical Performance (Per leg)

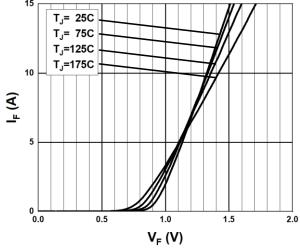


Fig. 1 Forward Characteristics

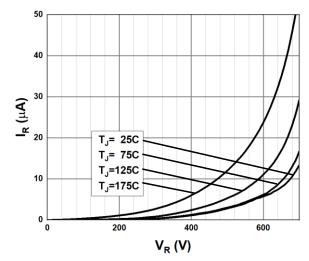


Fig. 2 Reverse Characteristics



Typical Performance (per leg)

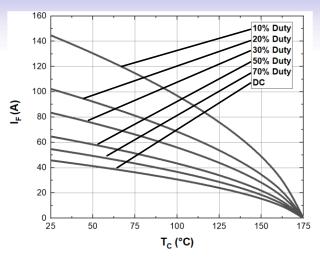


Fig. 3 Current Derating

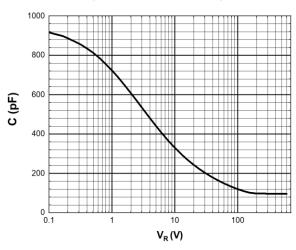


Fig. 5 Capacitance vs. Reverse Voltage

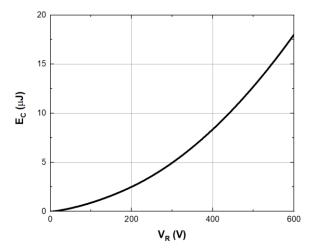


Fig. 7 Capacitance stored Energy

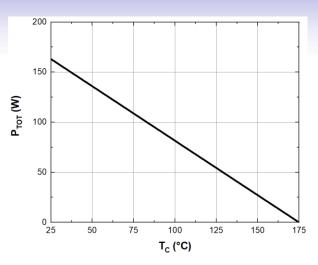


Fig. 4 Power Derating

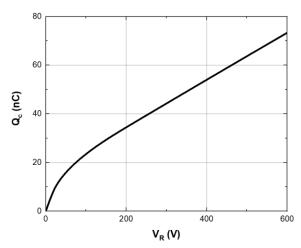


Fig. 6 Recovery Charge vs. Reverse Voltage

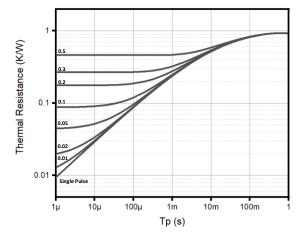
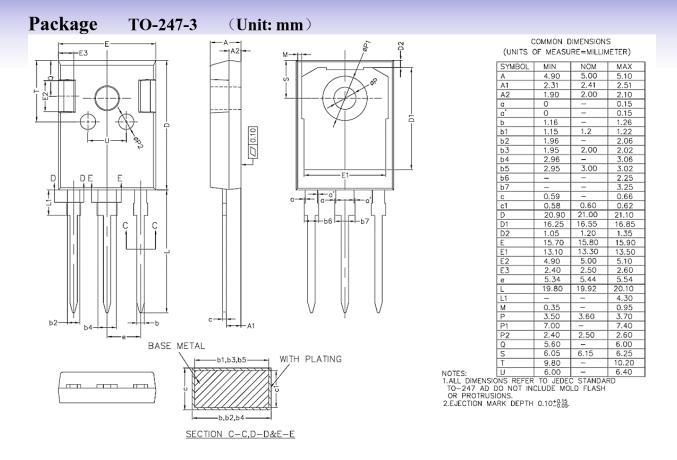


Fig. 8 Transient Thermal impedance

Page 3 of 4

S2D065V030D, Rev. 1.1





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